4. Energy Applications



Mitglied de Leibniz-Gemeins

Doping of Nanowires

- Doping during CVD growth
 - Co-doping in growth chamber (B₂H₆, B(CH₃)₃, PH₃ besides SiH₄)
- Post-growth doping
 - Spin on doping
 - Gaseous environment
 - Ion implantation (B, P)



Doping during CVD growth

Preparation: CVD from SiH₄ with B_2H_6 bzw. PH₃



- boron doping of NWs during growth (> 10¹⁸ cm⁻³)
- tapering of NWs
- different NW density and orientation
- easily nano-crystalline wires @ high doping levels

XTEM

40 nm



Post-growth Spin-on-Doping





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Doping of nanowires

- Doping during CVD growth
 - Co-doping in growth chamber $(B_2H_6, B(CH_3)_3, PH_3 besides SiH_4)$

- off Trade doping levels & good materials quality;

- Post-growth doping
 - Spin on doping
 - Gaseous environment

optimized t/T schemes for homogeneous dopant distribution possible? •full NW doping possible?



high between

odopant gradients within NWs

annealing to be determined;



Doping of nanowires by Ion implantation

- Control over doping profile Advantage:
- Disadvantage: additional processing steps
- Novelty in nanowires: diodes realized (working device)



S. Hoffmann, VAS et al., Nano Letters 9 (4), 1341–1344 (2009)



Electron Beam Induced Current (EBIC) • EBIC to locate *p*-*n* junctions

EBIC = Electron Beam Induced Current



S. Hoffmann, VAS et al., Nano Letters 9 (4), 1341–1344 (2009)



n doped *p* doped **Depleted** region

> Image based on current flowing at each pixel



Junctions in ion implanted nanowires

Nanomanipulator equiped with Ptlr tips



S. Hoffmann, VAS et al., Nano Letters 9 (4), 1341–1344 (2009)



Ptlr tip Nanowire

Nanomanipulator Setup



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5 cm

Junctions in ion implanted nanowires

Pt(90)/Ir(10)-tip: Schottky contact for *n* doped (P, 1.2×10^{19} cm⁻³; resistivity in Si~10⁻²Wcm; NW: d=200nm x I=400nm \rightarrow resistance ~100kW) SiNWs R^{up} tells that the NWs have successfully been doped by implantation & annealing R^{up} undoped Si NWs: 4 orders of magnitude higher resistivity **EBIC** signal at contact interface





Conclusions

- pn-junctions in NWs by respective doping
 - Successful realization of pn-junctions in working diodes by ion implantation •
 - High doping levels realized (10¹⁹cm⁻³)
 - Good flexibility in choice of doping levels
 - Suitable junction abruptness by portion wise doping (various implantation energies used to dope at different depths from the surface; dopant concentrations add up to a net doping profile)
- **Electrical characterization of nanowires**
 - EBIC is used to identify the pn-junction area •
 - In situ IV-measurements (nanomanipulation setup in an SEM) used to identify doping level and NW • resistivity



Solar Cell Based on SiNWs



Fig. 4. *J-V* curve for measured 5 μ m-diameter wire array. Efficiency = 5.7%, *V*_{oo} = 505 mV, *J*_{so} = 19.7 mA/cm², *FF* = 57.7 %, total cell area 12.9 mm², wire array area 4 mm².

M.D. Kelzenberg et al., Nano Lett. 8, 710 (2008)







 of the radial pn juncnt on the top surface. irs of the high-aspect s optically thick (thickption coefficient of the nority carriers are less inction.



Problematic: Gold Contamination







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Koren et al., Nano Lett., 2011, 11 (1), pp 183-187

Semiconducting nanowires grown by the vapor-liquid-solid method commonly develop nonuniform doping profiles both along the growth axis and radially due to unintentional surface doping and diffusion of the dopants from the nanowire surface to core during synthesis. We demonstrate two approaches to mitigate nonuniform doping in phosphorus-doped Si nanowires grown by the vapor-liquid-solid process. First, the growth conditions can be modified to suppress active surface doping. Second, thermal annealing following growth can be used to produce more uniform doping profiles. Kelvin probe force microscopy and scanning photocurrent microscopy were used to measure the radial and the longitudinal active dopant distribution, respectively. Doping concentration variations were reduced by 2 orders of magnitude in both annealed nanowires and those for which surface doping suppressed.

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PV properties of solar cell based on SiNWs



Non illuminated and illuminated (AM1.5) I-V curves of SiNWs etched into a mc-p+nn+-Si layer on glass. SiNW are irradiated through the glass substrate (super-state configuration) and contacted by metal tips at four different sample positions.

V. Sivakov et al. Nano Lett., 9 (4),1549–1554 (2009)





Backgroung:SIS-Diode

- No pn-junction
- Insert tunnel barrier between both semiconductors \rightarrow fermi level pinning
- -> charge carrier separation is based on quantum mechanical tunneling of minority carriers through the barrier

Challenge: Transfer the planar wafer-based concept to a nanostructured substrate \rightarrow Reach higher efficiencies because of better light absorption



Song, D. & Guo, B. Journal of Physics D: Applied Physics, 2009, 42, 025103 VAS et al., Intech "Nanowires - Fundamental Research", ISBN 978-953-307-327-9, 45-80 (2011) B. Hoffmann, V. Sivakov et al. INTECH "Nanowires - Recent Advances", ISBN: 978-953-51-0898-6, Chapter10 (2012)

Conclusions



SIS_Cell.mp4

Nanowires based Solar Cell WORKS







Newton's Law of Gravity

$$F_g = G \frac{m_1 m_2}{r^2}$$





The Proverbial Apple

The famous story that Newton came up with the idea for the law of gravity by having an apple fall on his head is not true, although he did begin thinking about the issue on his mother's farm when he saw an apple fall from a tree.

Friedrich August Kekulé said that he had <u>discovered</u> the ring shape of the benzene molecule <u>after having a reverie or day-</u> <u>dream</u> of a snake seizing its own tail.This vision, he said, came to him <u>after years of</u> <u>studying the nature</u> of carbon-carbon bonds.

Observation of NATURE!!!!!



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Energy Detachment





11 H₂O 1K 4.2 kJ/1.16 Wh

VAS et al., J. Phys. Chem. C114, 3798–3803 (2010) VAS, Journal of Nanoelectronics and Optoelectronics, 7(6) 583 (2012)





energy_detachment.AVI

Solar Hydrogen **Oxidation of Silicon** $Si + h\nu \rightarrow e^- + h^+$ $2H_2O + 4h^+ \rightarrow O_2 + 4H^+$ $4H^+ + 4e^- \rightarrow 2H_2$ $Si + 2H_2O \rightarrow SiO_2 + 2H_2$











5. Silicon Nanoparticles in Biomedicine



Motivation

Advanteges: - high porosity

- low Cytoxicity
- Metabolism in der Lever
- Photoluminescence
- formation simplicity



Application in Theranostics: **Thera**py + Diag**nostic**

→ Cancer markers and treatment (Drug-Delivery-Agent) [1]

→ Antibacterial/Antiviral Effects [2][3]

→ non toxic, fluoreszierende Farbstoffe für Multi-Photonenmikroskopie [1][3]

[1] Norah O'F. et al: "Silicon nanoparticles: applications in cell biology and medicine"
[2] Elena P. et al: "Bactericidal activity of black silicon"
[3] Wendelin S.: "Nanopartikel in biologischen Systemen"







Existing Biomaterials for DDS

Carbon nanotubes

",-": are not metabolized \rightarrow must be eliminated after administration

Bio-Glass

- one of the first completely synthetic materials that seamlessly bonds to bone; developed by Prof. L.Hench in 1967
- "-": containes at least four components (SiO₂, Na₂O, CaO, P₂O₅) that may influence negatively under certain conditions

(! Microporous Si showed much less level of Ca and Na)

Q-Dots

used as dyes (20 times brighter and 100 times more stable than commonly used fluorescent dyes)

• ",-": in vivo toxicity! \rightarrow Inhibition of the cell growth and viability, especially cadnium (CdSe) or lead-containing QDs



Biomedical Application of Silicon

1990 Prof. Leigh Canham \rightarrow **PL properties of SiNPs** (new approach of manufactory by electrochemical and chemical dissolution steps \rightarrow two-dimensional quantum size effects \rightarrow emission far above the band gap of bulk crystalline Si)

 $1995 \rightarrow$ in vitro studies of microporous Si films in simulated body fluids

- \rightarrow Induced hydroxyapatite growth on Si that is absent in isolation
- \rightarrow Bioactivity of porous Si: bonding with living soft tissue and bone
- \rightarrow Resorbability of porous Si
- → Biocompatibility of porous Si
- \rightarrow Low toxicity
- \rightarrow Biodegradable
- \rightarrow Luminescent \rightarrow Bioimaging
- \rightarrow Drug delivery

- L. T. Canham, "Bioactive silicon structure fabrication through nanoetching techniques", Adv. Mater., 7, 1995
- L. T. Canham, "Bioactive polycrystalline silicon", Adv. Mater., 8, 1996
- L. T. Canham, "The effects of DC electric currents on the in-vitro calcification of bioactive silicon wafers", Adv. Mater., 8, 1996



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Requirements for delivering materials





Biocompability

Biodegradation



- Lysosomal activity - Membrane permeability

> LDHe - Membrane permeability

SULFORHODAMINE B - Cell proliferation - Total protein synthesis rate





M. Sailor et al., Nature Materials 8, 332 (2009); Biomaterials 24, 1959 (2003)



GLUCOSE - General physiological cell state - Glucose consumption

MTT/XTT Mitochondrial metabolism ~ - Respiratory toxicity

CRISTAL VIOLET
 Cell proliferation
 - DNA





In vivo monitoring of Silicon

nature materials

PUBLISHED ONLINE: 22 FEBRUARY 2009 | DOI: 10.1038/NMAT2398

LETTERS

Biodegradable luminescent porous silicon nanoparticles for *in vivo* applications

Ji-Ho Park^{1,2}, Luo Gu¹, Geoffrey von Maltzahn³, Erkki Ruoslahti⁴, Sangeeta N. Bhatia^{3,5,6} and Michael J. Sailor^{1,2,7}*

Nanocontainers from Porous Si NPs



 \rightarrow Injected PSi particles are fully degradated into silicic acid and cleared by excretion via the kidneys





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THERANOSTICS THERAPY and DIAGNOSTICS.

Porous Si: non-toxic and biodegradable (bio-friendly)

- drug delivery carrier
- flexible therapy modalities (photo-, thermo-, ultrasound, em-rf, etc.)

Two-in-one concept



Adv. Drug Deliv. Rev., 60, 2008



Breast Cancer



World Health Organization, Breast Cancer Facts & Figures 2011-2012, http://www.cancer.org/acs/groups/content/@epidemiologysurveilance/documents/document/acspc-030975.pdf



How to visualize Si nanoparticles?



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Top-Down Silicon Nanostructures

SEM LD-SiNWs











TEM





SiNPs Formation

wet chemical etching

ultrasound depletion from the surface

Mechnianical milling

Forces upto 30 g possible

J ipht J

electrochemical etching

PoSiNP emission graphs with different excitation wavelengths (normalised)



290 nm 320 nm 350 nm 380 nm 402 nm



Silicon Nanoparticles Applications in Nanomedicine



Digital micrograph of the silicon nanoparticles suspension irradiated by a UV lamp at a wavelength of 366 nm. Visible red-orange emission is coming from the porous SiNPs prepared by top-down approach.

- Novel drug delivery agent based on biocompatible and biodegradable silicon nanoparticles
- Silicon nanoparticles application in nanomedicine (cancer, antivirulicid and antiseptic)



Silicon Nanoparticles Applications in Nanomedicine



UV-Lampe 254 nm + 366 nm

N2-Laser

Digital micrograph of the silicon nanoparticles suspension irradiated by a UV lamp and nitrogen laser. Visible red-orange emission is coming from the porous SiNPs prepared by top-down approach.



Silicon Nanoparticles Applications in Nanomedicine



Multi-photons microscopy image of E-Coli culture labelled with Silicon NPs (red-orange emission).

Problem: Photoluminescence of Silicon nanopartices der Partikellösung not stable for the longer time in water-containing solutions

- \rightarrow Functionalization
- \rightarrow Dextrane as cover (Bloodplasma-alternative)
 - Incapsulation and formation of agglomerates
 - Photoluminescence long-tim stability (>6)

Wochen)



Water

Digital photos of silicon nanoparticles in different media after 6 weeks of storage.

Ethanol Dextrane



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Bioimaging with SiNWs Cell line: MCF-7 (Michigan Cancer Foundation - 7) a breast cancer cell line

Labeling:

405nm – cell nucleus: DAPI 488nm – cell body: Calcein AM

561 nm / 642nm – Si

WF

peptide complexes

A. Jost und R. Heintzmann, Annu. Rev. Mater. Res., Bd. 43(1), 261, 2013. L. Schermelleh, R. Heintzmann, und H. Leonhardt, J. Cell Biol., 190(2), 165, 2010.



5 µm SIM

Wide-field (WF, left) and SIM (right) imaging of MCF-7 cells transfected with Cy5-coupled siRNA-





Transmission images and fluorescence microscopy images (HR-SIM image) of MCF-7 cells transfected with lowly doped ((a) and (c)) and heavily doped ((b) and (d)) filtered SiNPs generated by the transmitted light and HR-SIM (top view (xy)) and yz and xz cross-sections); nucleus staining Hoechst 34580 (blue, 405 nm), actin staining Alexa Fluor® 488 Phalloidin (green, 488 nm); SiNPs photoluminescence autofluorescence is measured at 642 nm (red). The incubation time is 5 h for (a) and (b) and 24 h for (c) and (d).

E. Tolstik, VAS, et al., ACS Nano, in press (2015).



Bioimaging with SiNWs



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Non-invasive Raman Imgaing



Raman microscopy images of MCF-7 cells transfected (a) with heavily doped and (b) with lowly doped (below) filtered SiNPs generated by the transmitted light and by Raman imaging (xyand xz- cross-sections of the reconstructed Raman image with SiNPs depicted in red within cell interior depicted the in blue). (C) Corresponding to them SiNPs spectrum (depicted in red) and MCF-7 cell interior spectrum based on the protein composition (depicted in blue). Incubation time is 6 h, 9 h and 24 h; the scale bar is 10 µm



Light Penetration







The photoacoustic (PA), also referred as optoacoustic, eect was rst introduced by Alexander Graham Bell in 1880. He found that absorption of electromagnetic waves by a medium generated sound waves. Even though the PA efect was known for a long time, it was not until 1994 that Kruger demonstrated application of this phenomenon in highly scattering media. It was applied a few years later to biomedical imaging.







Optical modalities benefit from high contrast due to electromagnetic interaction with materials, particularly absorption. Absorption in a biological tissue can be modeled with the well-known Beer-Lambert law:

```
I = I_0 xexp(-\mu_a L) (1)
```

where I is the intensity after light has traveled L meters, I_0 is the initial intensity and μ_a is the absorption coefficient.

High resolution (1-10µm) can be obtained in optical imaging because of the short wavelengths used, typically between 650 and 1350 nm. The major problem in optical imaging is the penetration depth. Biological tissue scatters light a lot. By replacing μ_a by μ_s , the Beer-Lambert law presented in Eq.1 can also be used to model scattering. This coefficient (μ_s) is around 1-10 mm⁻¹ in biological tissue. This means that the major part of the incident light has scattered after one millimeter. Scattering increases with shorter wavelengths, this is why near infrared (NIR) light is mostly used in optical biomedical imaging. Since photons that have not scattered form the signal of interest, maximal imaging depth rarely exceeds 3 mm. Diffuse optical tomography extends the penetration depth by detecting diffuse photons. This requires complex algorithms and suffers from poor spatial resolution.

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On the other hand, ultrasound imaging, also known as echography, relies on acoustic waves to study a tissue. High resolution (100µm) can also be obtained with short wavelengths, because they can resolve smaller details. In addition, penetration depth is in the order of centimeters to a few tens of centimeters. The down side is that the signal of interest is reflected waves due to changes in the speed of sound and these changes are relatively small. Therefore, contrast is poor in ultrasound imaging. Functional information is provided by Doppler imaging, where the velocity of fluids such as blood is imaged.

Photoacoustic tomography (PAT) aims to use the advantages of both optical and ultrasound imaging, without the disadvantages. This is done by illuminating the sample with diffuse, short pulses and collecting the ultrasound waves generated by the PA effect.



The basic idea of the photoacoustic effect is simple. Light is shone on a sample which absorbs a fraction of the incident energy. This energy is converted into heat. The temperature rise leads to thermoelastic expansion of the object. This sudden pressure rise propagates as a sound wave, which can be detected. By detecting the pressure waves, we can localize their source (i.e., where light was absorbed) and obtain important information about the studied sample.























Dr. Jithin Jose

Vevo LAZR Photoacoustic Imaging System



SiNPs based theraphy?



Mitglied de Leibniz-Gemeins

at Room Temperature



• Quantum efficiency of the SO generation: $h_{SO} = \eta_{PL} h_E \sim 5$ %

Suppression of the cancer cell proliferation by photo-excited nc-Si

The decrease of cancer cells (mouse fibroblasts) number was observed in suspensions of silicon nanocrystals under illumination. This decrease is explained by the effect of singlet oxygen photosensitized by nc-Si.

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Set up of in vivo experiments

L.Osminkina, VAS, et al., Nano Research Letters (2014)

Leibniz-

In Vitro Effect of Low Intensity MHz-ultrasound + Dextran-coated PSi NPs

- Heating
- Cavitation
- Nano-scalpels

2 MHz, 1 W/cm²

Cancer Theranostics

Container with Doxirubicin upto 20800 mg/g

Fei P. et al: "Silicon-Nanowire-Based Nanocarriers with Ultrahigh Drug-Loading Capacity for In Vitro and In Vivo Cancer Therapy", Angewangt Chemie International Edition. Leibniz-Gemeinsc

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0,1-0,5 Ωcm; 0,1M AgNO₃ 60 s

Bacteria@Viruses

Inhibition of Virusies

Derease of viruses in patient

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Antibactericidic Effect of SiNPs

- Destruction of cell wall
- therapeutic ultrasound (1W/cm²; 1,5 MHz, 15 min)

[3] Wendelin S.: "Nanopartikel in biologischen Systemen"

Antibactericidic Effect of SiNPs

Antibakterielle Wirkung von Silizium-Nanopartikeln bei E.Coli

Antibakterielle Wirkung von Silizium-Nanopartikeln bei S. aureus

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Conclusions

Silicon nanopartices can be succefully applied in nanomedicine as effective anti-cancer agent, as drug delivery agent and as possible therapeutica and disinfection agent. Quantum yiled (PL) was observed over 4%.

To do: photostability, surface modification and functionalization. Optimization of NPs particles for imiging technology

Thanks for your attention!

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DFG Deutsche Forschungsgemeinschaft

Bundesministerium für Bildung und Forschung

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Thanks for your attention!

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Motivation

Smart Material

Smart Technology

Smart Concept

Atomic Layer Deposition

- Part of Chemical-Vapour-Deposition (CVD) technique
- Temperature range from room temperature to several hundred degree Celsius
- Atmospheric to ultra high vacuum pressure
- Cyclic layer by layer deposition process
- Self-limited process

 \rightarrow Maximal one atomic layer per cycle

 \rightarrow High uniform film growth

Atomic Layer Deposition

Example: thermal Al₂O₃-Process a) Dosis-Step (TMA) b) Purge Chamber by inertgas c) Dosis-Step (H_2O) d) Purge Chamber by inertgas

- Surface should be saturated by precursor Long enough purge time to remove precursor and
- reaction products
- Next to only thermal processing, possibility to activate precursor by plasma

- One Monolayer TMA absorption on surface
- adsorpted TMA react with H_2O to AI_2O_3

Overview possible Deposition Compounds

	Q
_	

PU

				18
				2
				He
14	15	16	17	
6	7	8	9	10
С	N	0	F	Ne
14	15	16	17	18
Si	P	S	CI	Ar
32	33	34	35	36
Ge	As	Se	Br	Kr
50	51	52	53	54
Sn	Sb	Те	1	Xe
82	83	84	85	86
Pb	Bi	Po	At	Rn

February 2005

68	69	70	71
Er	Tm	Yb	Lu
100	101	102	103
Fm	Md	No	Lr

Oxford OpAL – Atomic Layer Deposition Engine

ALD Technology

ALD: Gao, Ley, Physik,

Uni Erlangen

Leibniz-Gemein

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ALD Technology

Very homogeneous distribution of ZnO inside the nanowire carpet

Leibniz-Ge

Transparent Conductive Oxides (TCO)

- Organic light emitting diodes (OLED)
- Liquid crystal displays (LCD)
- **Touch panels**
- Thin film solar cells

Indium Tin Oxide

- Low specific resistivity: ~ $10^{-5} \Omega$ cm
 - Poor raw material
 - \rightarrow high cost

Aluminium Zinc Oxide

Present specific resistivity: $\sim 10^{-4}$ Ωcm Better transmission in visible range Low cost

Transparent Conductive Oxides (TCO)

Farbication of AI doped ZnO using Atomic Layer Deposition

Precursors: Diethylzinc (DEZ) Trimethylaluminium (TMA) • Water (H_2O) **Doping Sequence:** N cycles DEZ/H₂O + 1 cycle TMA/H₂O

→ Doping Ratio 1/N

Minimal specific resistivity:

 $1/15 \ge best ratio \ge 1/20$

Stoichiometry measurement (with RBS):

Doping Ratio	Zn [%]	O [%]	AI [%]
1/10	47.1	52.9	6.6
1/20	49.8	50.2	2.9
1/30	51.0	49.0	2.0

Doping Ratio

Transparent Conductive Oxides (TCO) Influence of Deposition Temperature

Influence on:

- Impurity doping of ZnO
- Cristallinity
- **Dopant** activation
- \rightarrow specific resisitivity **XRD** pattern of ZnO:

Best results:

 temperatures ≥ 200°C doping ratio > 1/10

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Transparent Conductive Oxides (TCO)

about 90% in visible range

independent of doping and deposition temperature

Transparent Conductive Oxides (TCO) Flash Annealing

Flash Annealing System:

- © by Dresden Thin Film Technology
- Improvement of conductivity at all doping ratios
- Specific resistivity decrease up to 20%

- Short impulsiength of a few hundred microseconds • High energy up to 120 J/cm² • temperature sensitiv substrates

